

6MBP35VFN120-50

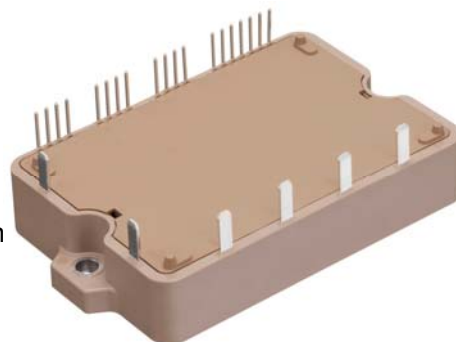
IGBT Modules

IGBT Module (V series)

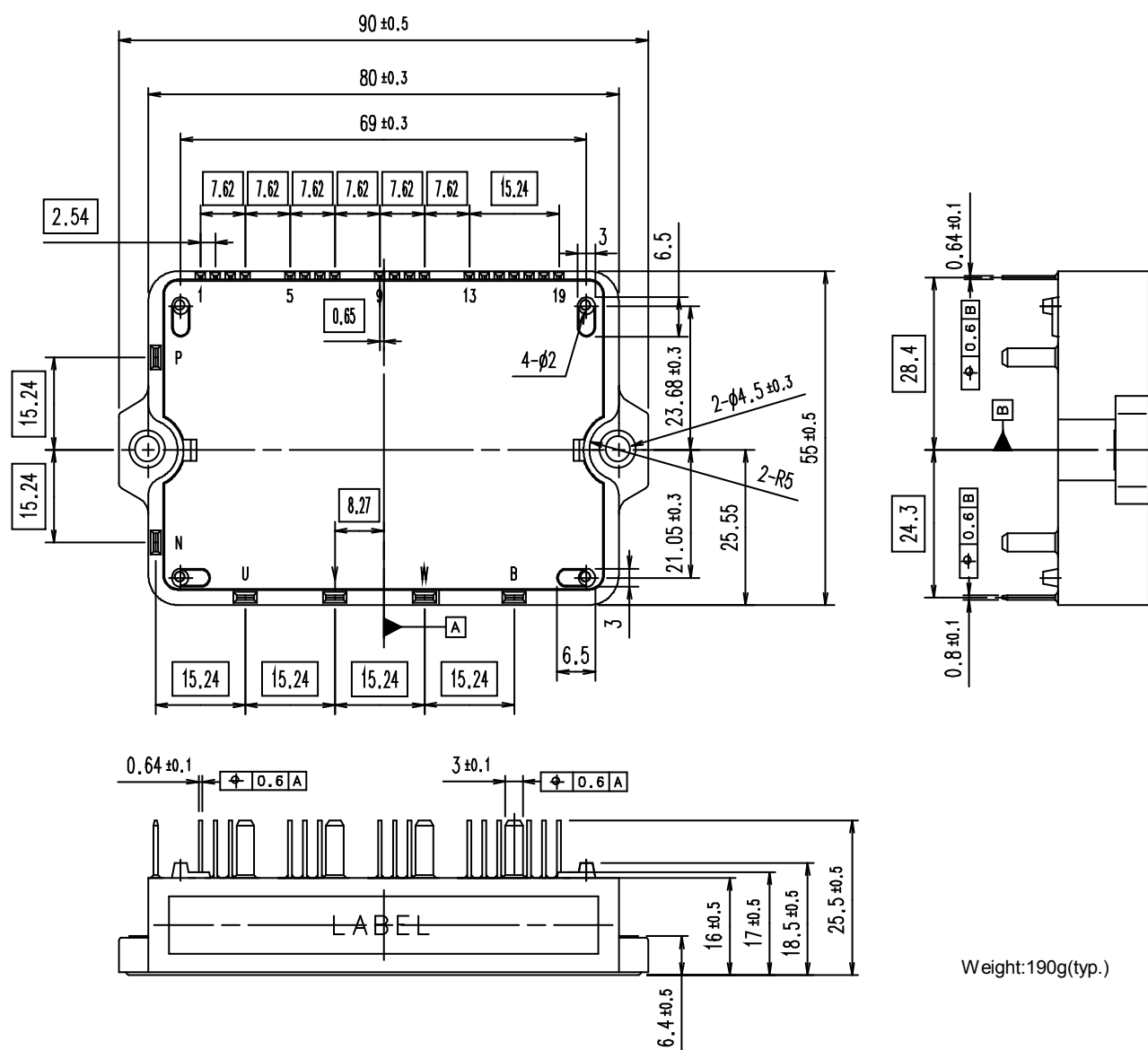
1200V / 35A / IPM

■ Features

- Temperature protection provided by directly detecting the junction temperature of the IGBTs
- Low power loss and soft switching
- High performance and high reliability IGBT with overheating protection
- Higher reliability because of a big decrease in number of parts in built-in control circuit



■ Outline drawing (Unit : mm)



Weight:190g(typ.)

6MBP35VFN120-50

IGBT Modules

■ Absolute Maximum Ratings

 $T_c = 25^\circ\text{C}$, $V_{CC} = 15\text{V}$ unless otherwise specified.

Items			Symbol	Min.	Max.	Units
Collector-Emitter Voltage *1			V _{CES}	0	1200	V
Short Circuit Voltage			V _{SC}	400	800	V
Inverter	Collector Current	DC	I _C	-	35	A
		1ms	I _{CP}	-	70	A
		Duty=100% *2	-I _C	-	35	A
Collector Power Dissipation		1 device *3	P _C	-	290	W
Brake	Collector Current	DC	I _C	-	-	A
		1ms	I _{CP}	-	-	A
	Forward Current of Diode		I _F	-	-	A
Collector Power Dissipation		1 device *3	P _C	-	-	W
Supply Voltage of Pre-Driver *4			V _{CC}	-0.5	20	V
Input Signal Voltage *5			V _{in}	-0.5	V _{CC} +0.5	V
Alarm Signal Voltage *6			V _{ALM}	-0.5	V _{CC}	V
Alarm Signal Current *7			I _{ALM}	-	20	mA
Junction Temperature			T _j	-	150	°C
Operating Case Temperature			T _{opr}	-20	110	°C
Storage Temperature			T _{stg}	-40	125	°C
Solder Temperature *8			T _{sol}	-	260	°C
Isolating Voltage *9			V _{iso}	-	AC2500	V _{rms}
Screw Torque		Mounting (M4)	-	-	1.7	Nm

Notes

*1: V_{CES} shall be applied to the input voltage between terminal P-(U,V, W,B) and (U,V, W,B)-N.

*2: Duty=125 $^\circ\text{C}$ /R_{th(j-c)}D/(I_F×V_F Max.)×100

*3: $P_C = 125^\circ\text{C}/R_{th(j-c)}Q$ (Inverter & Brake)

*4: V_{CC} shall be applied to the input voltage between terminal No.4 and 1, 8 and 5, 12 and 9,14 and 13.

*5: V_{in} shall be applied to the input voltage between terminal No.3 and 1, 7 and 5, 11 and 9,15~18 and 13.

*6: V_{ALM} shall be applied to the voltage between terminal No.2 and 1, 6 and 5, 10 and 9,19 and 13.

*7: I_{ALM} shall be applied to the input current to terminal No.2,6,10 and 19.

*8: Immersion time 10±1sec. 1time

*9: Terminal to base, 50/60Hz sine wave 1min. All terminals should be connected together during the test.

■ Electrical Characteristics ($T_j = 25^\circ\text{C}$, $V_{CC} = 15\text{V}$ unless otherwise specified.)

● Main circuit

Item		Symbol	Conditions		Min.	Typ.	Max.	Units
Inverter	Collector Current at off signal input	ICES	VCE = 1200V		-	-	1.0	mA
	Collector-Emitter saturation voltage	VCE(sat)	IC = 35A	Terminal	-	-	2.20	V
				Chip	-	1.7	-	V
	Forward voltage of FWD	VF	IF = 35A	Terminal	-	-	2.65	V
Chip				-	2.1	-	V	
Brake	Collector Current at off signal input	ICES	VCE =		-	-	-	mA
	Collector-Emitter saturation voltage	VCE(sat)	IC =	Terminal	-	-	-	V
				Chip	-	-	-	V
	Forward voltage of FWD	VF	IF =	Terminal	-	-	-	V
Chip				-	-	-	V	
Switching time		ton	VDC = 600V , Tj=125°C		1.1	-	-	μs
		toff			-	-	2.1	μs
		trr	VDC = 600V IF = 35A		-	-	0.3	μs

6MBP35VFN120-50

IGBT Modules

● Control circuit

Item	Symbol	Conditions		Min.	Typ.	Max.	Units
Supply current of P-side pre-driver (per one unit)	I _{ccp}	Switching Frequency = 0-15kHz Tc=-20~110°C		-	-	11	mA
Supply current of N-side pre-driver	I _{ccn}			-	-	33	mA
Input signal threshold voltage	V _{in} (on)	Vin-GND	ON	1.2	1.4	1.6	V
	V _{in} (off)		OFF	1.5	1.7	1.9	V

● Protection Circuit

Item	Symbol	Conditions	Min.	Typ.	Max.	Units
Over Current Protection Level	I _{oc}	T _j =125°C	70	-	-	A
Over Current Protection Delay time	t _{dOC}	T _j =125°C	-	5	-	μs
Short Circuit Protection Delay time	t _{sc}	T _j =125°C	-	2	3	μs
IGBT Chips Over Heating Protection Temperature Level	T _{jOH}	Surface of IGBT Chips	150	-	-	°C
Over Heating Protection Hysteresis	T _{jH}		-	20	-	°C
Under Voltage Protection Level	V _{UV}		11.0	-	12.5	V
Under Voltage Protection Hysteresis	V _H		0.2	0.5	-	V
Alarm Signal Hold Time	t _{ALM(OC)}	ALM-GND	1.0	2.0	2.4	ms
	t _{ALM(UV)}	T _c = -20~110°C	2.5	4.0	4.9	ms
	t _{ALM(TjOH)}		5.0	8.0	11.0	ms
Resistance for current limit	R _{ALM}		960	1265	1570	Ω

■ Thermal Characteristics (T_c = 25°C)

Item	Symbol	Min.	Typ.	Max.	Units
Junction to Case Thermal Resistance*10	Inverter IGBT	-	-	0.43	°C/W
	Inverter FWD	-	-	0.62	°C/W
	Brake IGBT	-	-	-	°C/W
	Brake FWD	-	-	-	°C/W
Case to Fin Thermal Resistance with Compound	R _{th(c-f)}	-	0.05	-	°C/W

*10: For 1device , the measurement point of the case is just under the chip.

■ Noise Immunity (V_{DC}=600V, V_{CC}=15V)

Item	Conditions	Min.	Typ.	Max.	Units
Common mode rectangular noise	Pulse width 1μs,polarity ±,10min. Judge: no over-current, no miss operating	±2.0	-	-	kV

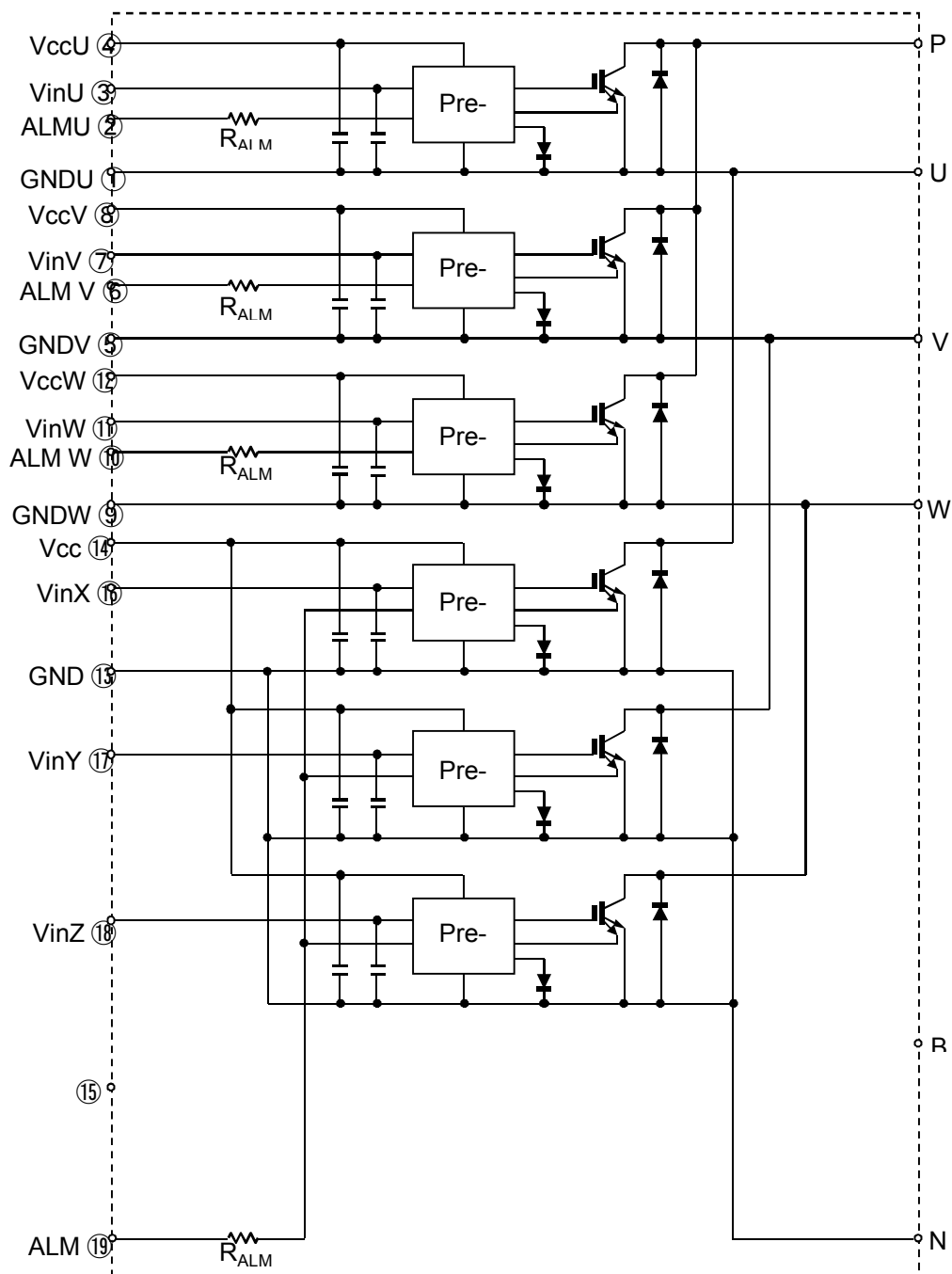
■ Recommended Operating Conditions

Item	Symbol	Min.	Typ.	Max.	Units
DC Bus Voltage	V _{DC}	-	-	800	V
Power Supply Voltage of Pre-Driver	V _{CC}	13.5	15.0	16.5	V
Switching frequency of IPM	f _{sw}	-	-	20	kHz
Arm shoot through blocking time for IPM's input signal	t _{dead}	1.0	-	-	μs
Screw Torque (M4)	-	1.3	-	1.7	Nm

6MBP35VFN120-50

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■ Block Diagram



Pre-drivers include following functions

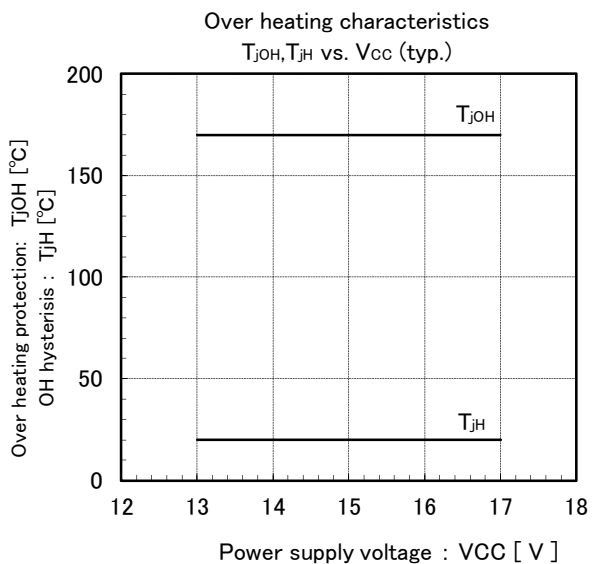
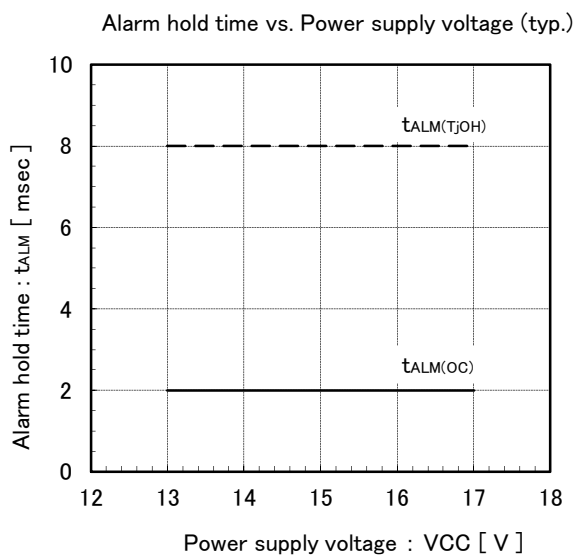
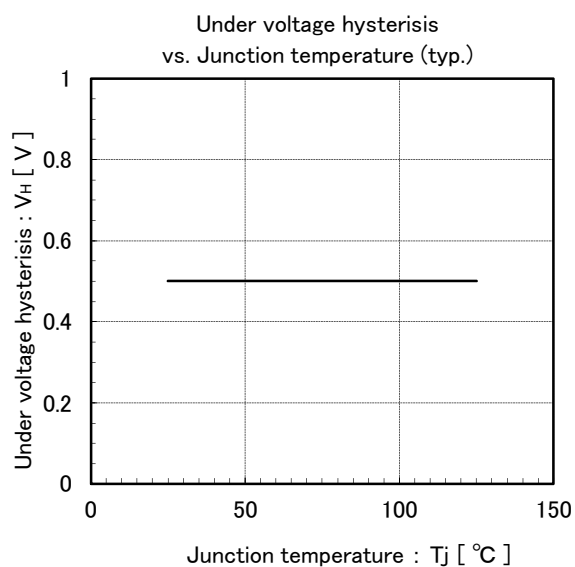
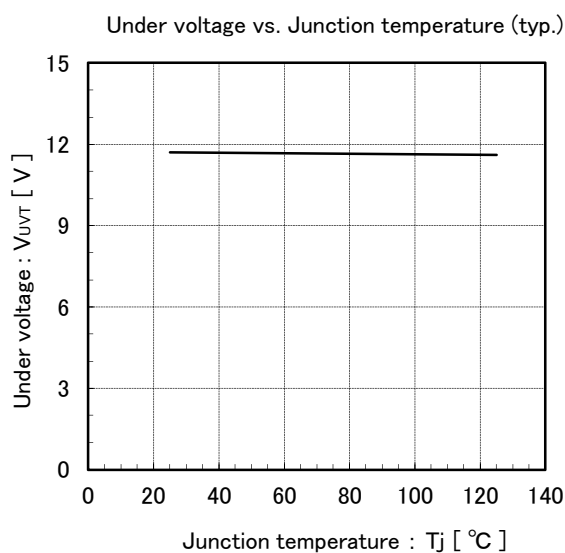
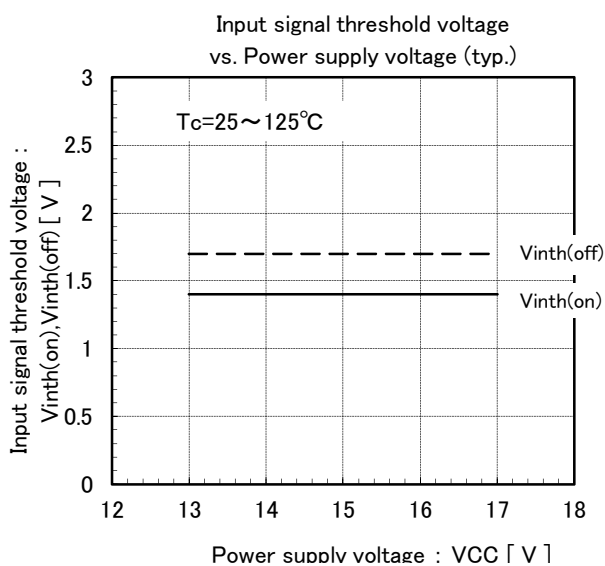
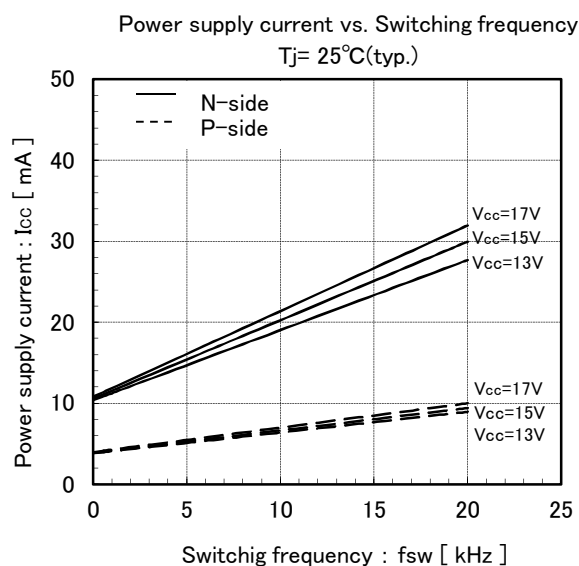
1. Amplifier for driver
2. Short circuit protection
3. Under voltage lockout circuit
4. Over current protection
5. IGBT chip over heating protection

6MBP35VFN120-50

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■ Characteristics (Representative)

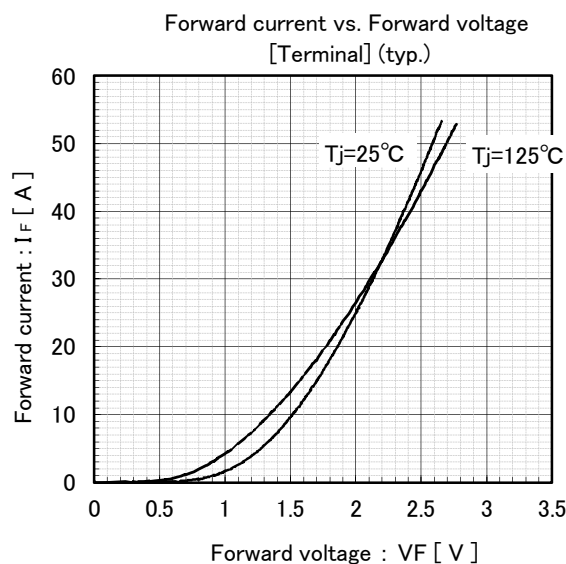
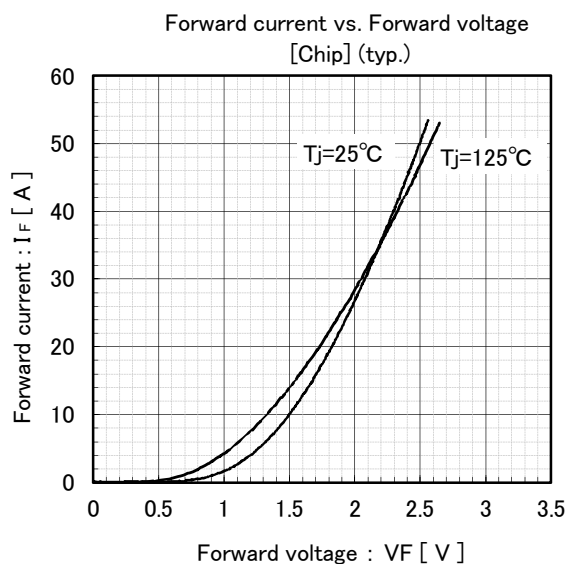
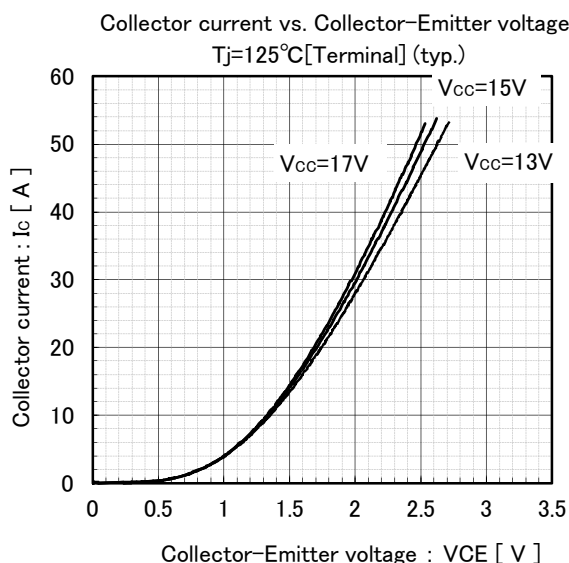
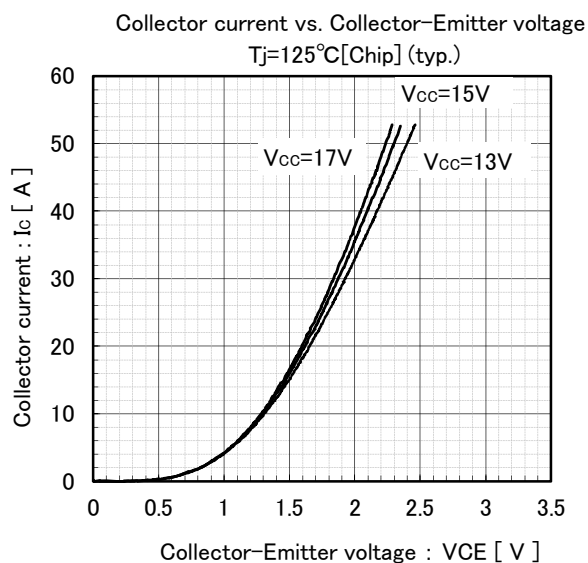
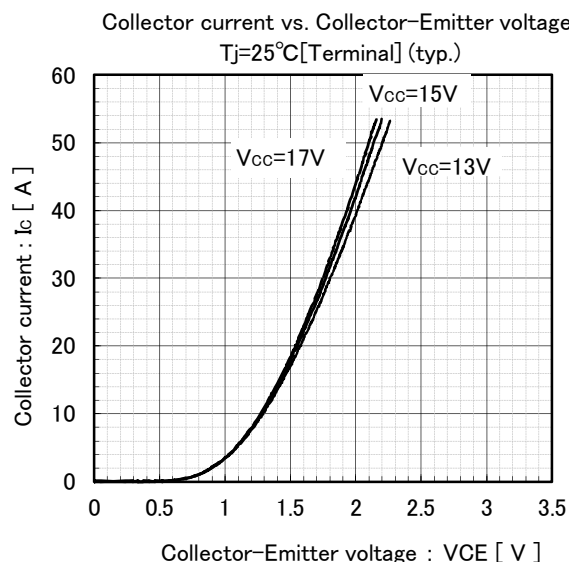
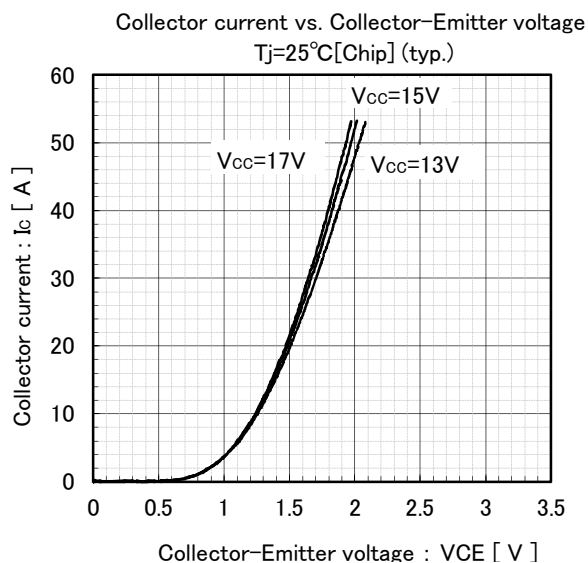
● Control Circuit



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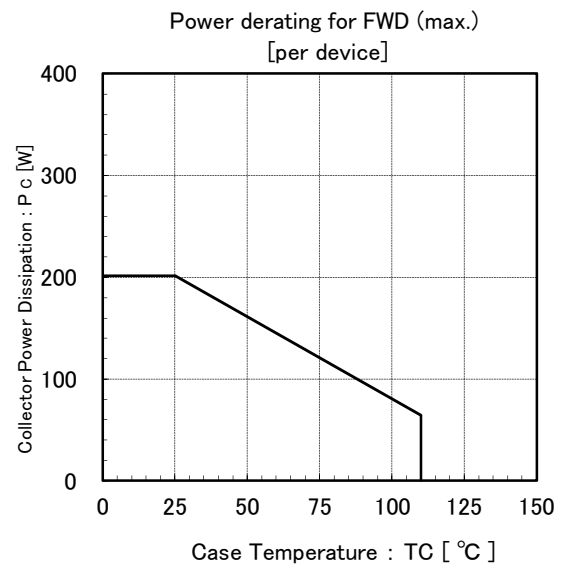
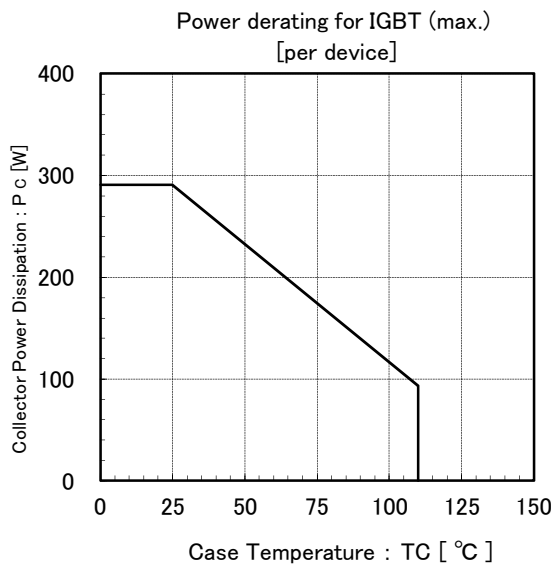
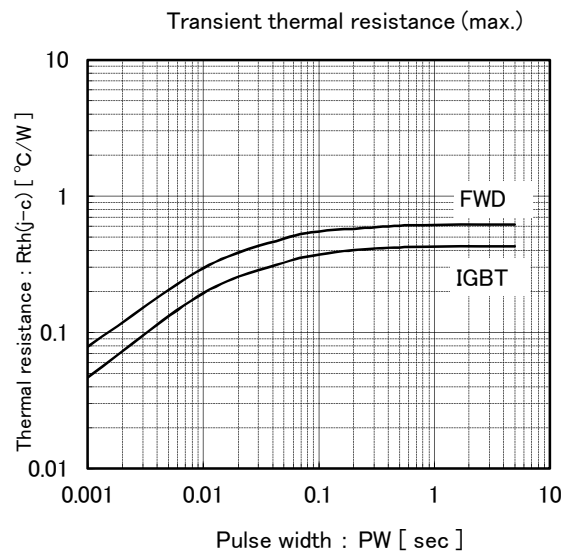
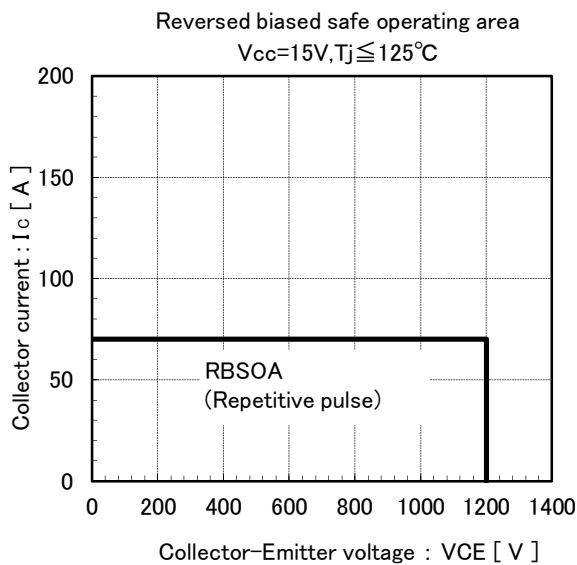
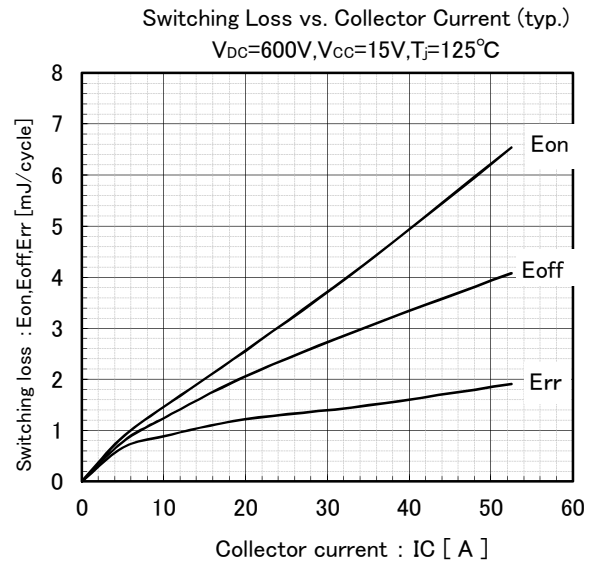
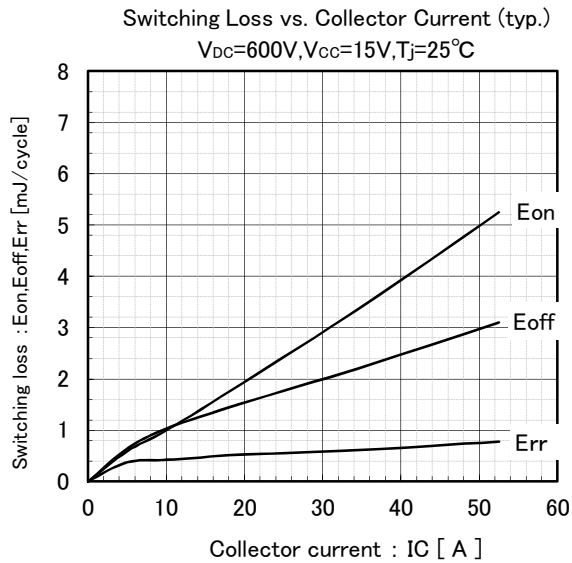
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● Inverter



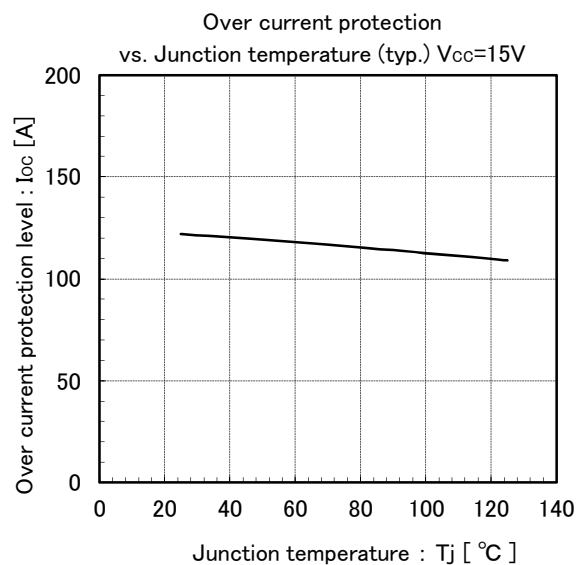
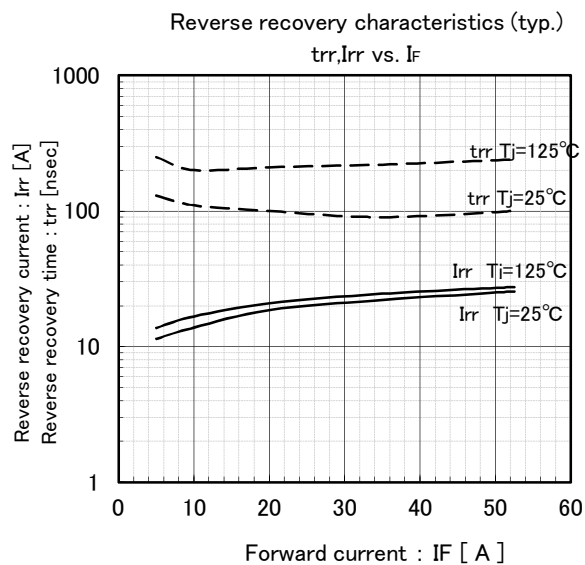
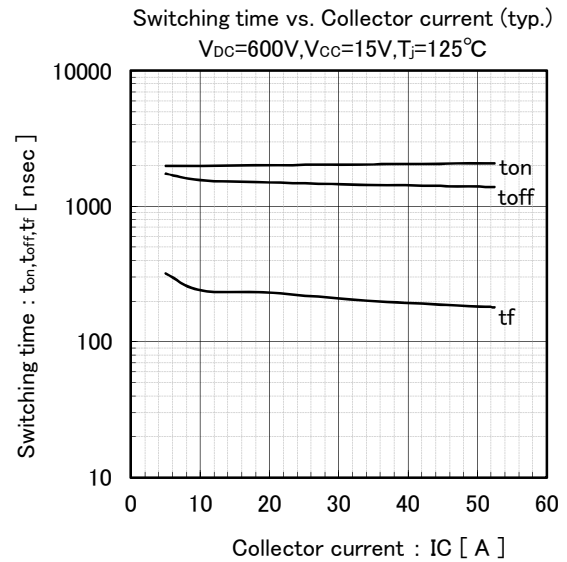
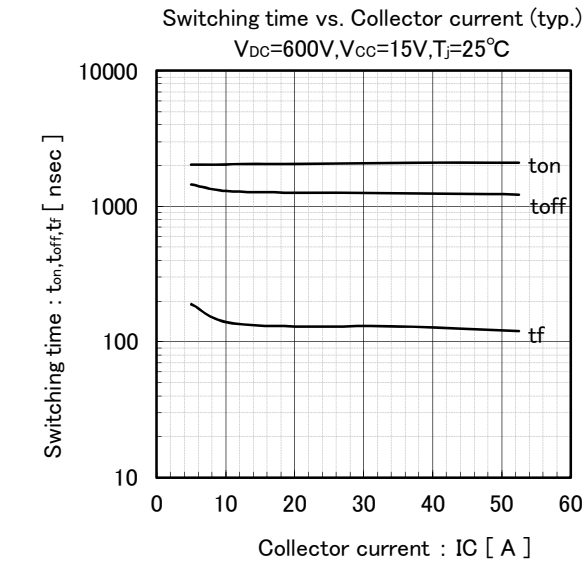
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